

Contents

Preface XV

1	Introduction and Review of Electronic Technology	1
1.1	Introduction: Functions of Electronic Technology	6
1.1.1	Review of Electronic Devices	6
1.1.2	Sources of Current and Voltage: DC	6
1.1.2.1	Batteries: Lithium Ion, Ni–Cd, NiMH, and “Supercapacitors”	6
1.1.2.2	Thermionic Emitters	10
1.1.2.3	Field Emitters	13
1.1.2.4	Ferroelectric and Pyroelectric Devices	15
1.1.3	Generators of Alternating Current and Voltage: AC	16
1.1.3.1	Faraday Effect Devices	16
1.1.3.2	Crystal Oscillators	17
1.1.3.3	Gunn Diode Oscillators	18
1.1.3.4	Esaki Diodes	19
1.1.3.5	Injection Lasers	20
1.1.3.6	Organic Light Emitting Diodes	21
1.1.3.7	Blackbody Emission of Radiation	22
1.1.4	Detectors	23
1.1.4.1	Photomultiplier and Geiger Counter	24
1.1.4.2	Photodetector, Solar Cell, and pn Junction	25
1.1.4.3	Imaging Detector, CCD Camera, and Channel Plate	26
1.1.4.4	SQUID Detector of Magnetic Field and Other Quantities	26
1.1.5	Two-Terminal Devices	27
1.1.5.1	Semiconductor pn Junction (Nonohmic)	27
1.1.5.2	Metal–Semiconductor Junction and Alternative Solar Cell	29
1.1.5.3	Tunnel Junction (An Ohmic Device)	30
1.1.5.4	Josephson Junction	30
1.1.5.5	Resonant Tunnel Diode (RTD, RITD)	33
1.1.5.6	Spin-Valve and Tunnel-Valve GMR Magnetic Field Detectors	33
1.1.6	Three-Terminal Devices	34

1.1.6.1	Field Effect Transistor	35
1.1.6.2	Bipolar Junction Transistors: npn and pnp	37
1.1.6.3	Resonant Tunneling Hot-Electron Transistor (RHET)	37
1.1.7	Four-Terminal Devices	38
1.1.7.1	Thyristors: npnp and pnpn	38
1.1.7.2	Dynamic Random Access Memory	38
1.1.7.3	Triple-Barrier RTD (TBRTD)	38
1.1.8	Data Storage Devices	38
1.1.8.1	Optical Memory Devices	38
1.1.8.2	Electrical Computer Memory Devices	39
	References	40
2	From Electronics to Nanoelectronics: Particles, Waves, and Schrödinger's Equation	41
2.1	Transition from Diffusive Motion of Electron Fluid to Quantum Behavior of Single Electrons	41
2.1.1	Vacuum Triode to Field Effect Transistor to Single Electron Transistor	42
2.1.2	Crystal Detector Radio to Photomultiplier and Gamma Ray Detector	45
2.2	Particle (Quantum) Nature of Matter: Photons, Electrons, Atoms, and Molecules	46
2.2.1	Photons	46
2.2.2	Electrons	47
2.2.3	Atoms, Bohr's Model	48
2.2.3.1	Quantization of Angular Momentum and Orbit Energy	49
2.2.3.2	Light Absorption and Emission Lines	50
2.2.3.3	Magnetic Moments of Orbiting Electrons	50
2.2.3.4	Stern–Gerlach Experiment and Electron Spin	51
2.3	Particle–Wave Nature of Light and Matter, De Broglie Formulas $\lambda = h/p$, $E = h\nu$	52
2.3.1	Wavefunction ψ , Probability Density $\psi^*\psi$, Traveling and Standing Waves	53
2.4	Maxwell's Equations	54
2.5	The Heisenberg Uncertainty Principle	57
2.6	Schrödinger Equation, Quantum States and Energies, Barrier Tunneling	58
2.6.1	Schrödinger Equations in One Dimension	59
2.6.2	The Trapped Particle in One Dimension	60
2.6.3	Reflection and Tunneling at a Potential Step	64
2.6.4	Penetration of a Barrier	66
2.6.5	Trapped Particles in Two and Three Dimensions: Quantum Dot	66
2.7	The Simple Harmonic Oscillator	67
2.8	Fermions, Bosons, and Occupation Rules	69
2.9	A Bose Particle System: Thermal Radiation in Equilibrium	70
	References	72

3	Quantum Description of Atoms and Molecules	75
3.1	Schrödinger Equation in Spherical Polar Coordinates	75
3.1.1	The Hydrogen Atom, One-Electron Atoms	75
3.1.2	Positronium and Excitons	79
3.1.3	Magnetization M , Magnetic Resonance, and Susceptibility χ	81
3.1.4	Electric Dipole Emission Selection Rules for Atoms	82
3.1.5	Spontaneous and Stimulated Emission of Light	83
3.2	Indistinguishable Particles and Their Exchange Symmetry	87
3.2.1	Symmetric and Antisymmetric Wavefunctions	87
3.2.2	Orbital and Spin Components of Wavefunction	88
3.2.3	Pauli Principle and Periodic Table of Elements	89
3.2.3.1	Filled Atomic Shells	89
3.2.3.2	Qualitative Aspects of Smallest Atoms	90
3.2.3.3	Alkali Atoms, Filled Core Plus One Electron	90
3.2.4	Carbon Atom $^{12}\text{C } 1s^2 2s^2 2p^2 \sim 0.07 \text{ nm}$	91
3.2.5	Cu, Ni, Xe, Hf	93
3.3	Molecules	95
3.3.1	Ionic Molecules	96
3.3.2	Covalent Bonding in Simple Molecules	97
3.3.2.1	Hydrogen Molecule Ion H_2^+	97
3.3.2.2	Hydrogen Molecule	99
3.3.2.3	Methane CH_4 , Ethane C_2H_6 , and Octane C_8H_{18}	101
3.3.2.4	Ethylene C_2H_4 , Acetylene C_2H_2 , and Benzene C_6H_6	102
3.3.2.5	Benzene Delocalized Orbitals, Diamagnetism	104
3.3.2.6	Diamagnetic Susceptibility of Benzene	107
3.3.2.7	Modeling Delocalized Electrons in a Ring	110
3.3.2.8	Other Ring Compounds, Electronic Polarizability	120
3.3.3	C_{60} Buckyball Molecule	124
	References	127
4	Metals, Semiconductors, and Junction Devices	129
4.1	Metals	129
4.1.1	Electronic Conduction	130
4.1.1.1	Resistivity, Mean Free Path	130
4.1.1.2	Hall Effect, Magnetoresistance	131
4.1.2	Metals as Boxes of Free Electrons	131
4.1.2.1	Fermi Level, DOS, Dimensionality	131
4.2	Energy Bands in Periodic Structures	136
4.2.1	Model for Electron Bands and Gaps, Electrons and Holes	138
4.2.2	Si, GaAs, and InSb	142
4.2.3	Semiconductors and Insulators: Electron Bands and Conduction	142
4.2.4	Hydrogenic Donors and Excitons in Semiconductors, Direct and Indirect Bandgaps	145
4.2.5	Carrier Concentrations in Semiconductors, Metallic Doping	146

4.3	pn Junctions, Diode I - V Characteristic, Photodetector, and Injection Laser	150
4.3.1	Radiative Recombination of Electron-Hole Pairs, Emission of Light	151
4.3.2	pn Junction Injection Laser	153
4.3.2.1	Increasing Radiative Efficiency η of the Injection Laser	155
4.3.2.2	VCSEL: Vertical Cavity Surface Emitting Laser	157
4.4	Semiconductor Surface: Schottky Barrier	158
4.5	Ferromagnets	159
4.5.1	The Exchange Interaction	159
4.5.2	Magnetization and Critical Temperature	160
4.5.3	Smallest Magnetic Domain: Superparamagnet	162
4.5.4	Separate Bands for Spin-Up and Spin-Down	163
4.5.5	Hard and Soft Ferromagnets	164
4.5.6	Spin-Dependent Scattering, Resistivities of Spin-Up versus Spin-Down	164
4.6	Piezoelectrics, Pyroelectrics, and Superconductors	166
4.6.1	Cooperative Distortions and Internal Fields	166
4.6.2	Piezoelectrics	166
4.6.3	Ferroelectrics and Pyroelectrics	167
4.6.4	Superconductors: Large-Scale Coherent Quantum Systems	167
4.6.4.1	Superconductivity: a Macroscopic Quantum State	168
4.6.4.2	The Superconducting Magnetic Flux Quantum	168
4.6.4.3	Josephson Junctions and the Superconducting Quantum Interference Detector (SQUID)	170
	References	173
5	Some Newer Building Blocks for Nanoelectronic Devices	175
5.1	The Benzene Ring, a Conceptual Basis	176
5.2	The Graphene sheet, a Second Conceptual Basis	177
5.2.1	Electronic Conduction in Graphene	177
5.2.2	Electronic Conduction in Epitaxial Bilayer Graphene	182
5.2.3	Device Potential for Graphene	184
5.3	Carbon Nanotubes and Related Materials	187
5.3.1	Rules and Nomenclature for Nanotubes	187
5.3.2	Physical Properties, Current Capacity	188
5.3.3	Electric Field Effects Based on Carbon Nanotubes	191
5.3.4	Ferromagnetic Nanotubes Controlled by Electron or Hole Doping	192
5.4	Gold, Si, and CdS Nanowires and a Related Device	193
5.4.1	Rules for One-Dimensional Conductors	193
5.4.2	Gold Atom Nanowire Conductors	194
5.4.3	Proposed Benzene-Vanadium Ferromagnetic Nanowire	195
5.4.4	Single-Nanowire Electrically Pumped CdS Laser	196

5.5	“Endohedral” C ₆₀ Buckyballs ~0.5 nm and Related Fullerene Molecules	198
5.6	Quantum Dots	199
5.7	Quantum Wells and the Two-Dimensional Electron Gas Metal (2DEG)	205
5.7.1	Quantum Well Infrared Photodetector	205
5.7.2	Two-Dimensional Metallic Electron Gas (2DEG)	206
5.8	Photonic Crystals	210
5.9	Organic Molecules and Conductive Polymers	213
5.9.1	Metallic Polymers	214
5.9.2	Semiconducting Polymers in Organic Light-Emitting Diodes	217
	References	221
6	Fabrication and Characterization Methods	223
6.1	Introduction	223
6.2	Surface Structuring	223
6.2.1	Nanopore Arrays in Polycarbonate	224
6.2.2	Dendritic Growths: Anopore Al ₂ O ₃ and TiO ₂ Nanotube Arrays	224
6.2.3	Completely Absorbing Nanostructured Surfaces	226
6.3	Specialized Vapor Deposition Processes	228
6.3.1	Chemical Vapor Deposition Methods	228
6.3.1.1	Nanowire Growth by Laser-Assisted Chemical Vapor Deposition	229
6.3.1.2	Carbon Nanotube Growth	230
6.3.2	Vapor Growth of Conducting Organic Single Crystals	232
6.4	Silicon Technology: The INTEL–IBM Approach to Nanotechnology	233
6.4.1	Patterning, Masks, and Photolithography	233
6.4.2	Etching Silicon	234
6.4.3	Depositing Highly Conducting Electrode Regions	236
6.4.4	Methods of Deposition of Metal and Insulating Films	236
6.5	Advanced Patterning and Photolithography	239
6.5.1	Ultraviolet and X-Ray Lithography	239
6.5.2	Electron Beam Lithography	240
6.5.3	Sacrificial Layers, Suspended Bridges, Single-Electron Transistors	241
6.6	Use of DNA Strands in Guiding Self-Assembly of Nanometer-Size Structures	243
6.7	Scanning Probe Sensing and Fabrication Methods	245
6.7.1	Moving Au Atoms, Making Surface Molecules	247
6.7.2	Assembling Organic Molecules with an STM	248
6.7.3	Atomic Force Microscope Arrays	249
	References	250
7	The Field Effect Transistor: Size Limits	251
7.1	Metal–Oxide–Silicon Field-Effect Transistor	251
7.1.1	Operating Principles of MOSFET	251

7.1.2	Constant Electric Field Scaling	253
7.1.3	Drain Currents at Present Limits of Scaling	255
7.2	Small Size Limits for the MOSFET	255
7.2.1	Nano-FET Drive Current I	256
7.2.2	Nano-FET Drive Current II	257
7.3	Present Status of MOSFET Fabrication and Performance	258
7.3.1	Working n- and p- MOSFET Devices with 5 nm Channel Length	259
7.4	Alternative to Bulk Silicon: Buried Oxide BOX	261
7.5	Alternative to Bulk Silicon: Strain Engineering	262
7.6	The Benzene Molecule as a Field Effect Transistor	263
	References	265
8	Devices Based upon Electron Tunneling: Resonant Tunnel Diodes	267
8.1	Introduction	267
8.2	Physical Basis of Tunneling Devices	267
8.2.1	Barrier Penetration and Trapped Particles	268
8.2.2	Escape Time from a Finite Well	270
8.2.3	Resonant Tunneling Diode	272
8.2.4	Time for Tunneling and Device Speed	272
8.2.5	Esaki Diode	275
8.3	Resonant Tunneling Diodes and Hot Electron Transistors	275
8.3.1	Three-Terminal Resonant Tunneling Device	276
8.3.2	“Resonant Interband Tunnel Diode”: A Relative of The Esaki Diode	277
8.4	Superconducting (RSFQ) Logic/Memory Computer Elements	279
8.5	Epitaxial MgO-Barrier Tunnel Junctions: Magnetic Field Sensors	285
	References	287
9	Single-Electron Transistors, Molecular and Hybrid Electronics	289
9.1	Introduction to Coulomb and Molecular Devices	289
9.2	Single-Electron (Coulomb) Transistor SET	290
9.2.1	Nanoscope Source–Drain Channel: Two Tunnel Junctions in Series	290
9.2.2	Single-Electron Transistor Model	292
9.2.3	A Single-Electron Transistor Based on a Single C ₆₀ Molecule	294
9.2.4	A Single-Electron Transistor Based on a Carbon Nanotube	294
9.2.5	The Radio Frequency Single-Electron Transistor (RFSET): A Proven Research Tool	294
9.3	Single Molecules as Active Elements in Electronic Circuits	297
9.4	Hybrid Nanoelectronics Combining Si CMOS and Molecular Electronics: CMOL	301
9.5	Carbon Nanotube Crossbar Arrays for Ultradense, Ultrafast, Nonvolatile Random Access Memory	302

9.6	Carbon Nanotube-Based Electromechanical Switch Arrays for Nonvolatile Random Access Memory	306
9.7	Proposed 16-bit Parallel Processing in a Molecular Assembly	307
	References	309
10	Devices Based on Electron Spin and Ferromagnetism for Storage and Logic	311
10.1	Hard and Soft Ferromagnets	312
10.2	The Origins of Giant Magnetoresistance	313
10.2.1	Spin-Dependent Scattering of Electrons	314
10.2.2	The GMR Spin Valve, a Nanoscale Magnetoresistance Sensor	315
10.2.3	The Tunnel Valve, a Better (TMR) Magnetic Field Sensor	316
10.3	Magnetic Random Access Memory	319
10.4	Hybrid Ferromagnet–Semiconductor Nonvolatile Hall Effect Gate Devices	320
10.5	Spin Injection: The Johnson–Silsbee Effect	321
10.5.1	Apparent Spin Injection from a Ferromagnet into a Carbon Nanotube	323
10.6	Imaging a Single Electron Spin by a Magnetic Resonance AFM	323
10.7	Magnetic Logic Devices: A Majority Universal Logic Gate	327
10.8	Magnetic Domain Wall Racetrack Memory	329
	References	332
11	Qubits Versus Binary Bits in a Quantum Computer	333
11.1	Introduction	333
11.1.1	Binary Bits and Qubits	333
11.2	Electron and Nuclear Spins and Their Interaction	337
11.3	A Spin-Based Quantum Computer Using STM	340
11.4	Double-Well Potential Charge Qubits	341
11.4.1	Coherent Bonding and AntiBonding States in Artificial Structure	341
11.4.2	Silicon-Based Quantum Computer Qubits	344
11.4.3	Experimental Approaches to the Double-Well Charge Qubit	345
11.4.4	Coupling of Two-Charge Qubits in a Solid-State (Superconducting) Context	349
11.5	Ion Trap on a GaAs Chip, Pointing to a New Qubit	351
11.6	Adiabatic Quantum Computation	353
11.6.1	An Example of an Optimization Problem	355
11.6.2	Demonstration of Adiabatic Quantum Computation	356
11.6.3	Flux Qubits as a Scalable Approach to Quantum Computation	357
	References	362
12	Applications of Nanoelectronic Technology to Energy Issues	365
12.1	Introduction	365
12.1.1	Limitation of Oil Resources	365
12.1.2	Alteration of Atmosphere	366

12.1.3	Improving Performance of Energy Components via Nanoelectronic Technology	366
12.1.4	Topics of Opportunity from Nanoelectronic Perspective	366
12.2	Solar Energy and Its Conversion	367
12.2.1	Photovoltaic Solar Cells	367
12.2.2	Thin Film Solar Cells Versus Crystalline Cells	375
12.2.3	CIGS ($\text{CuIn}_{1-x}\text{Ga}_x\text{Se}_2$) Thin Film Solar Cells	375
12.2.4	Dye-Sensitized Solar Cells	382
12.2.5	Polymer Organic Solar Cells	385
12.2.6	Comments on Cells and on Solar Power Versus Wind Power	389
12.3	Hydrogen Production (Solar) for Energy Transport	390
12.3.1	Economics of Hydrogen at Present	390
12.3.2	Hydrogen as Potential Intermediate in US Electricity Distribution	391
12.3.3	Efficient Photocatalytic Dissociation of Water into Hydrogen and Oxygen	393
12.3.4	C-Doped TiO_2 Nanotube Arrays for Dissociating H_2O by Light	401
12.4	Storage and Transport of Hydrogen as a Potential Fuel	403
12.5	Surface Adsorption as a Method of Storing Hydrogen in High Density	404
	References	407
13	Future of Nanoelectronic Technology	411
13.1	Silicon Devices	411
13.1.1	Power Density and Power Usage	413
13.1.2	Opportunity for Innovation in Large-Scale Computation	414
13.2	Solar Energy Conversion with Printed Solar Cells	416
13.2.1	Capital Costs per Unit Area for CIGS Cells	416
13.3	Emergence of Nanoimprinting Methods	420
13.4	Self-Assembly of Nanostructured Electrodes	421
13.5	Emerging Methods in Nanoelectronic Technology	424
	References	426
	Exercises	429
	Abbreviations	439
	Some Useful Constants	443
	Index	445